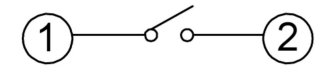


CIRCUIT DIAGRAM



SPECIFICATION

Contact Rating: 50mA, 12V DC
 Contact Resistance: 100mΩ max
 Insulation Resistance: 100mΩ min. 500V DC
 Dielectric Strength: 250V AC/1minute
 Travel: 0.25mm
 Operating Temp: -30°C ~ +85°C
 Storage Temp: -30°C ~ +80°C

PAPT NO	TS-1101VA-X-X-X
Operating Force	A:100gf B:160gf C:260gf
Height	H:3.5
Fixed column	A:With B:without
Keystake	A:PA46: B:Silica gel

⑤	Terminal	—	2	Brass (0.30t)	Plating silvering	—
④	Contact	—	1	F.ag/Sus	Natural	—
③	Base	—	1	Lcp		—
②	Cover	—	1	Brass	Plating Nickel	—
①	Keystake	—	1	Lcp		—
ITEM	PAPT NAMF	TER,NO	QTY	MATERIAL	FINISHING	REMARK

				ANGULAR	±5°
				L ≤ 4	±0.2
				4 < L ≤ 16	±0.3
				16 < L ≤ 63	±0.4
				L > 63	±0.5
	DATE	REVISED	APPROVED	UNSPECIFIED TOLERANCES	



DSND		SCALE: N/A	MODEL TYPE: TACT SWITCH
DWN		VIEW:	PART NO.: TS-1101VA-X-X-X
CHKD		UNIT: mm/in	DWG NO.:
APPD		SIZE: A4	
		WEIGHT	SHEET
			REVISIC
		1/1	A0

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